

2MBI300VD-120-50

IGBT Modules

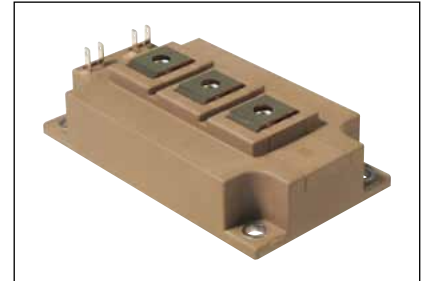
IGBT MODULE (V series) 1200V / 300A / 2 in one package

■ Features

- High speed switching
- Voltage drive
- Low Inductance module structure

■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial machines, such as Welding machines



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items	Symbols	Conditions	Maximum ratings	Units	
Collector-Emitter voltage	V _{CEs}		1200	V	
Gate-Emitter voltage	V _{GES}		±20	V	
Inverter	Collector current	Continuous	Tc=80°C 300		
			Tc=25°C 360		
		Ic pulse	1ms		600
		-Ic			300
		-Ic pulse	1ms		600
Collector power dissipation	Pc	1 device	2205	W	
Junction temperature	Tj		175	°C	
Operating junction temperature (under switching conditions)	Tjop		150		
Case temperature	Tc		125		
Storage temperature	Tstg		-40 ~ +125		
Isolation voltage	V _{iso}	AC : 1min.	2500	VAC	
Screw torque	Mounting (*2)		6.0	N m	
	Terminals (*3)		5.0		

Note *1: All terminals should be connected together during the test.

Note *2: Recommendable Value : 3.0-6.0 Nm (M5 or M6)

Note *3: Recommendable Value : 2.5-5.0 Nm (M6)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units		
			min.	typ.	max.			
Zero gate voltage collector current	I _{CEs}	V _{GE} = 0V, V _{CE} = 1200V	-	-	2.0	mA		
Gate-Emitter leakage current	I _{GES}	V _{CE} = 0V, V _{GE} = ±20V	-	-	400	nA		
Gate-Emitter threshold voltage	V _{GE(th)}	V _{CE} = 20V, I _c = 300mA	6.0	6.5	7.0	V		
Inverter	Collector-Emitter saturation voltage	V _{GE} = 15V I _c = 300A	V _{CE(sat)} (terminal)	Tj=25°C	-	2.00	2.45	V
				Tj=125°C	-	2.35	-	
				Tj=150°C	-	2.40	-	
				Tj=25°C	-	1.85	2.10	
				Tj=125°C	-	2.15	-	
	V _{CE(sat)} (chip)					2.00		
Input capacitance	C _{ies}	V _{CE} = 10V, V _{GE} = 0V, f = 1MHz	-	24.0	-	nF		
Inverter	Turn-on time	ton	V _{CC} = 600V	-	0.60	-	μs	
		tr	I _c = 300A	-	0.20	-		
		tr(i)	V _{GE} = ±15V	-	0.05	-		
Inverter	Turn-off time	toff	R _θ = 1.8Ω	-	0.80	-	μs	
		tf	Tj = 150°C	-	0.08	-		
Inverter	Forward on voltage	V _{GE} = 0V I _F = 300A	V _F (terminal)	Tj=25°C	-	1.85	2.25	V
				Tj=125°C	-	2.00	-	
				Tj=150°C	-	1.95	-	
				Tj=25°C	-	1.70	1.95	
				Tj=125°C	-	1.85	-	
	V _F (chip)					1.80		
Reverse recovery time	trr	I _F = 300A	-	0.15	-	μs		

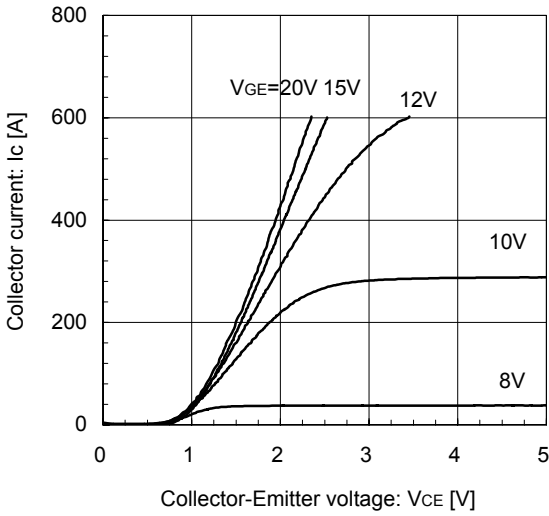
● Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance (1device)	R _{th(j-c)}	IGBT FWD	-	-	0.068	°C/W
Contact thermal resistance (1device) (*4)	R _{th(c-f)}	with Thermal Compound	-	0.013	-	

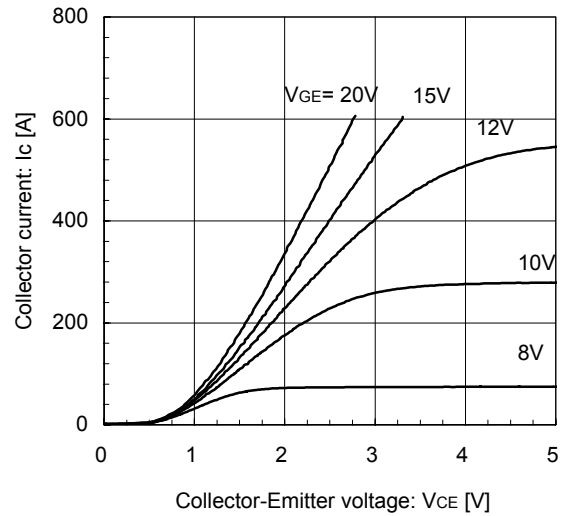
Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

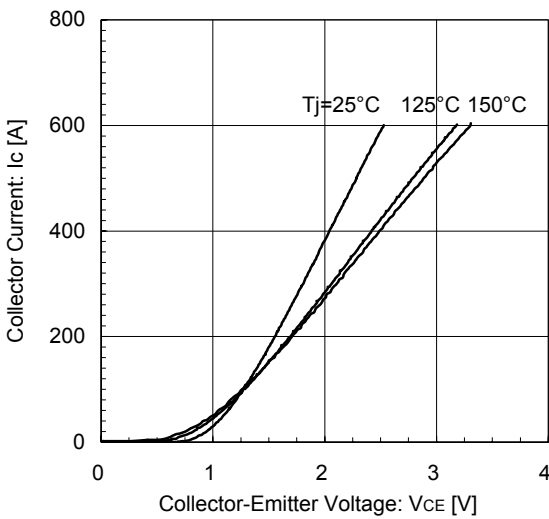
Collector current vs. Collector-Emitter voltage (typ.)
T_j = 25°C / chip



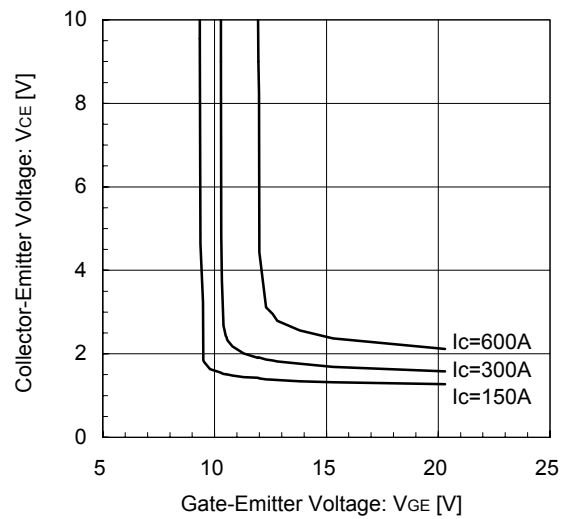
Collector current vs. Collector-Emitter voltage (typ.)
T_j = 150°C / chip



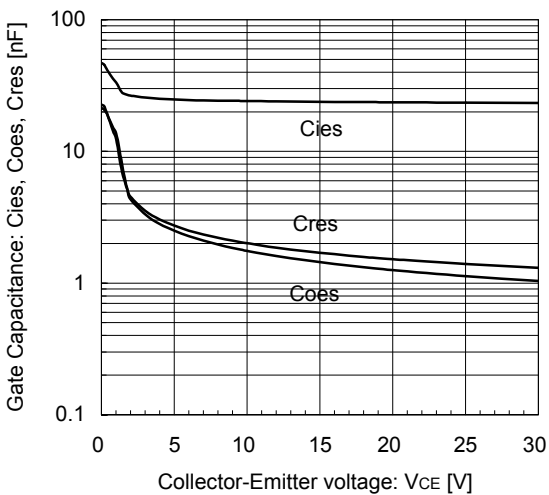
Collector current vs. Collector-Emitter voltage (typ.)
V_{GE} = 15V / chip



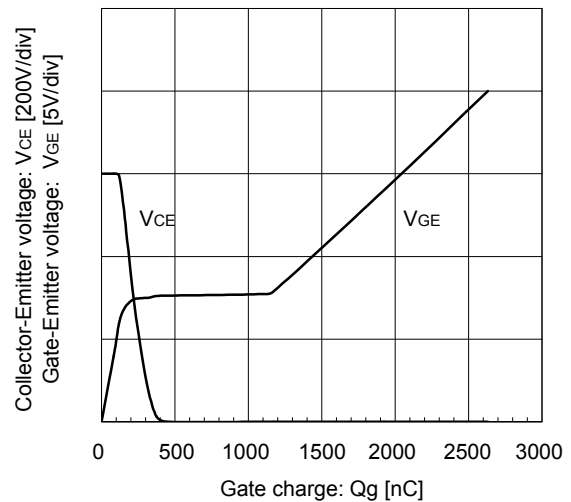
Collector-Emitter voltage vs. Gate-Emitter voltage
T_j = 25°C / chip



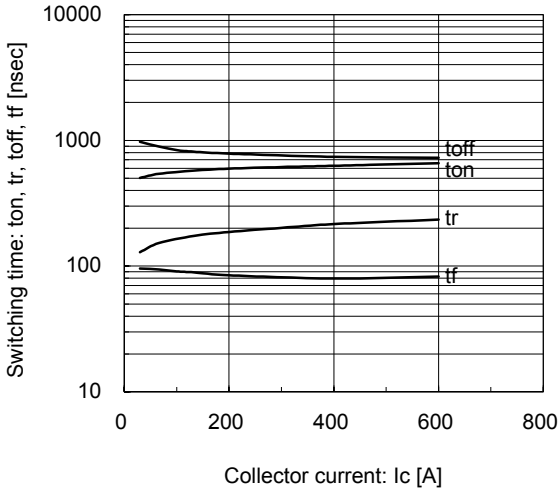
Gate Capacitance vs. Collector-Emitter Voltage
V_{GE} = 0V, f = 1MHz, T_j = 25°C



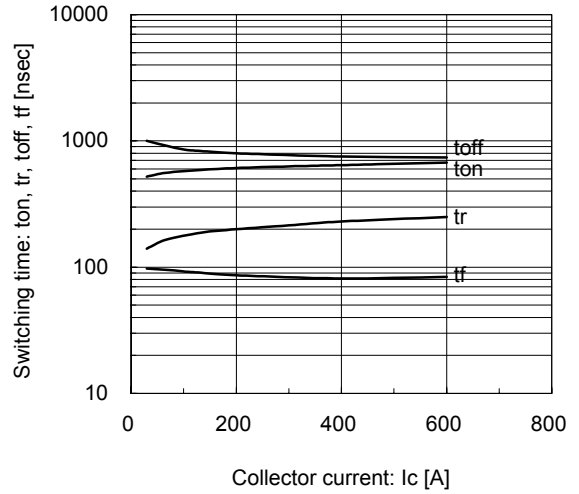
Dynamic Gate Charge (typ.)
V_{CC} = 600V, I_C = 300A, T_j = 25°C



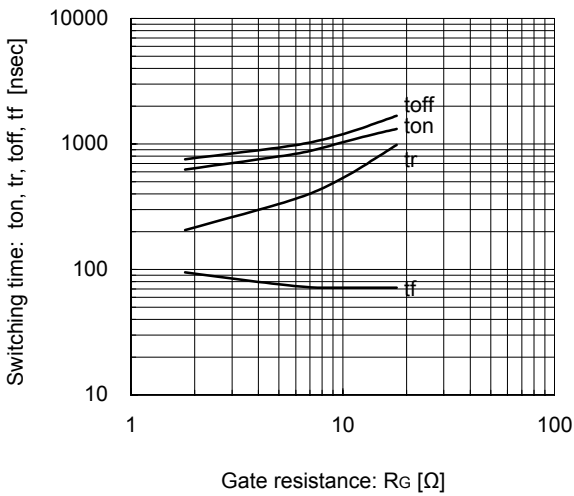
Switching time vs. Collector current (typ.)
 $V_{CC}=600V, V_{GE}=\pm 15V, R_G=1.8\Omega, T_j=125^\circ C$



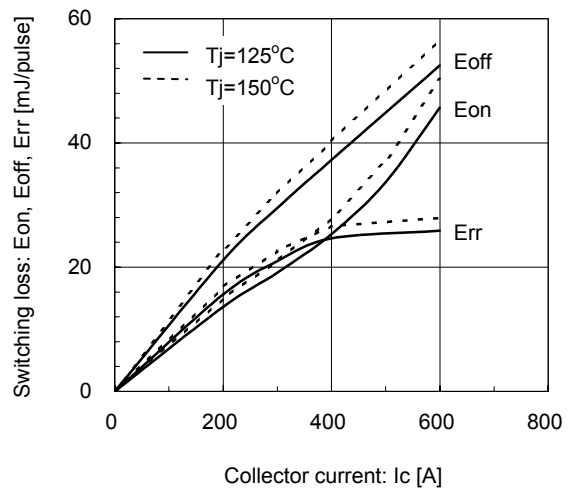
Switching time vs. Collector current (typ.)
 $V_{CC}=600V, V_{GE}=\pm 15V, R_G=1.8\Omega, T_j=150^\circ C$



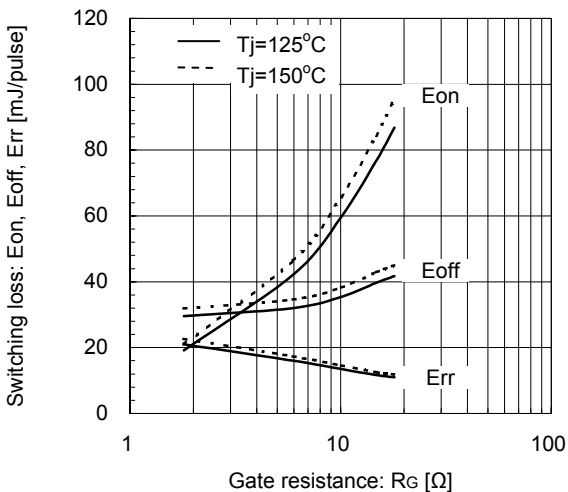
Switching time vs. Gate resistance (typ.)
 $V_{CC}=600V, I_c=300A, V_{GE}=\pm 15V, T_j=125^\circ C$



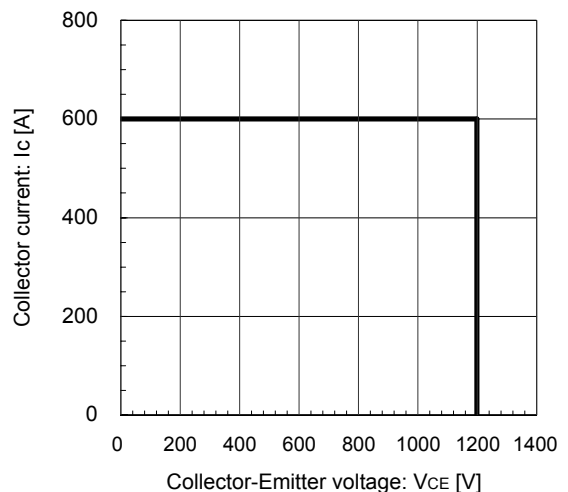
Switching loss vs. Collector current (typ.)
 $V_{CC}=600V, V_{GE}=\pm 15V, R_G=1.8\Omega, T_j=125, 150^\circ C$



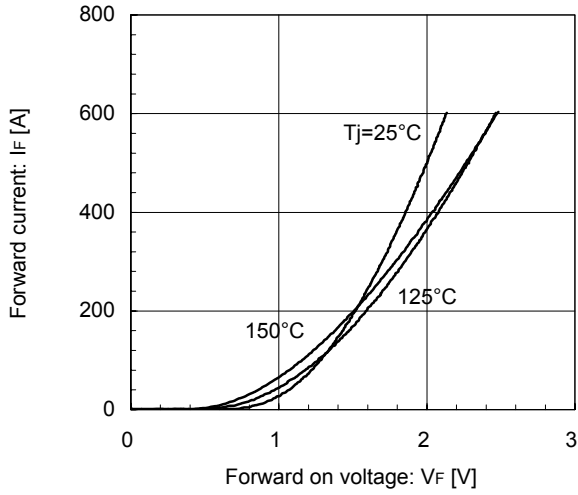
Switching loss vs. Gate resistance (typ.)
 $V_{CC}=600V, I_c=300A, V_{GE}=\pm 15V, T_j=125, 150^\circ C$



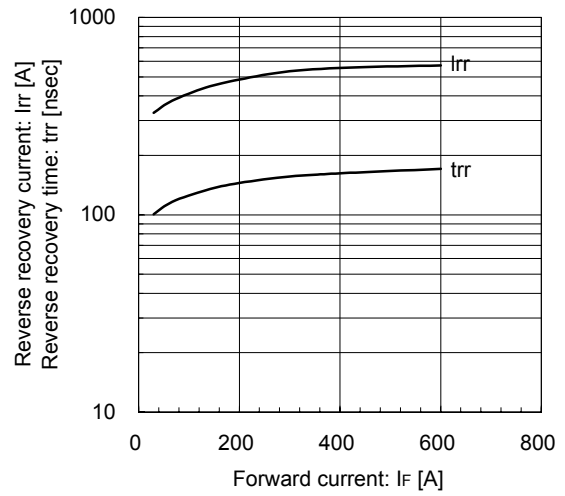
Reverse bias safe operating area (max.)
 $+V_{GE}=15V, -V_{GE}=15V, R_G=1.8\Omega, T_j=150^\circ C$



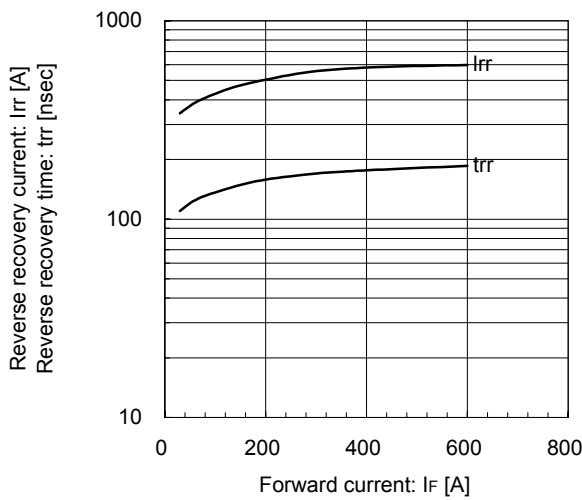
Forward Current vs. Forward Voltage (typ.)
chip



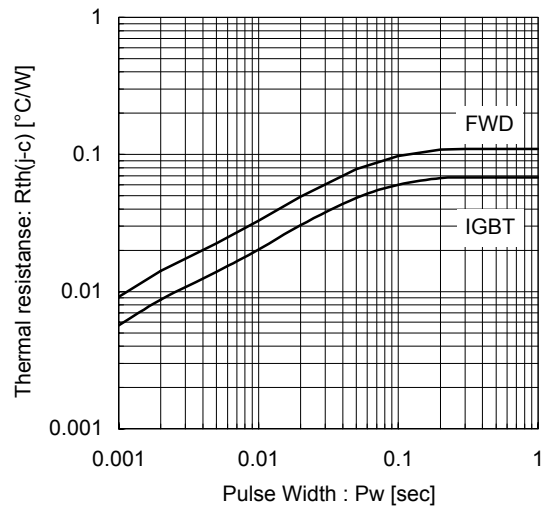
Reverse Recovery Characteristics (typ.)
V_{CC}=600V, V_{GE}=±15V, R_G=1.8Ω, T_J=125°C



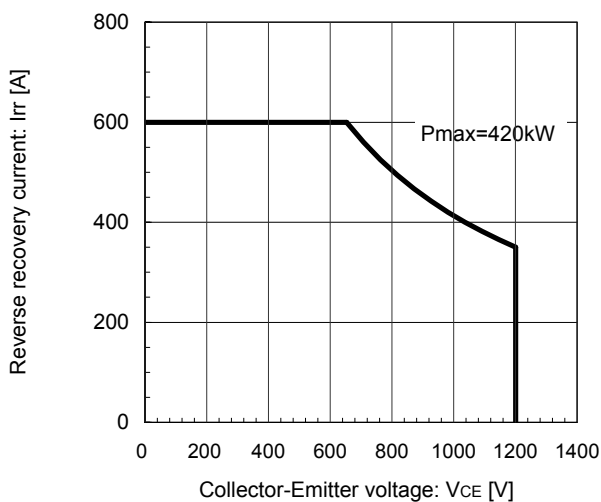
Reverse Recovery Characteristics (typ.)
V_{CC}=600V, V_{GE}=±15V, R_G=1.8Ω, T_J=150°C



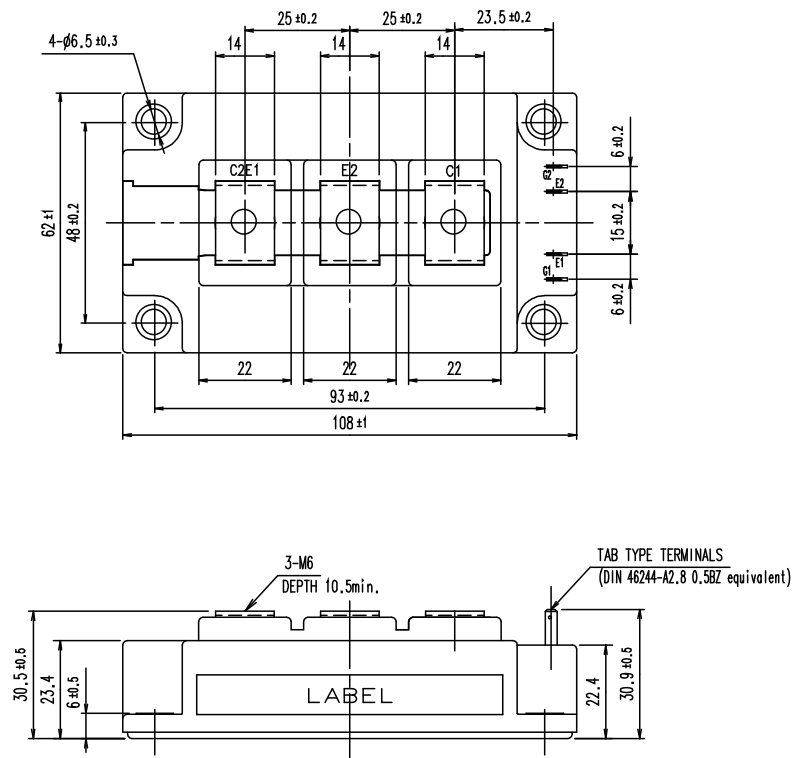
Transient Thermal Resistance (max.)



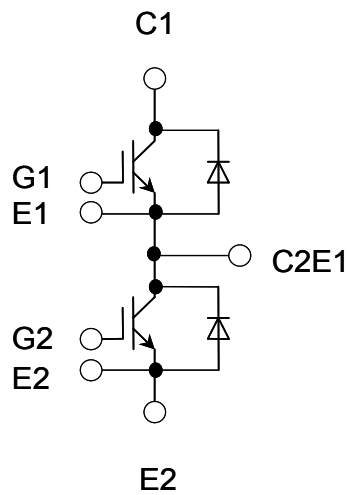
FWD safe operating area (max.)
T_J=150°C



■ Outline Drawings, mm



■ Equivalent Circuit Schematic



WARNING

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